

FGA25S125P

1250 V, 25 A Shorted-anode IGBT

Features

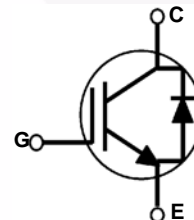
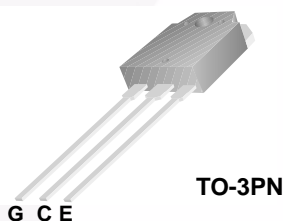
- High Speed Switching
- Low Saturation Voltage: $V_{CE(sat)} = 1.8\text{ V @ } I_C = 25\text{ A}$
- High Input Impedance
- RoHS Compliant

Applications

- Induction Heating, Microwave Oven

General Description

Using advanced field stop trench and shorted-anode technology, Fairchild's shorted-anode trench IGBTs offer superior conduction and switching performances for soft switching applications. The device can operate in parallel configuration with exceptional avalanche capability. This device is designed for induction heating and microwave oven.



Absolute Maximum Ratings

Symbol	Description	Rating	Unit
V_{CES}	Collector to Emitter Voltage	1250	V
V_{GES}	Gate to Emitter Voltage	± 25	V
I_C	Collector Current @ $T_C = 25^\circ\text{C}$	50	A
	Collector Current @ $T_C = 100^\circ\text{C}$	25	A
$I_{CM(1)}$	Pulsed Collector Current	75	A
I_F	Diode Continuous Forward Current @ $T_C = 25^\circ\text{C}$	50	A
	Diode Continuous Forward Current @ $T_C = 100^\circ\text{C}$	25	A
P_D	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	250	W
	Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$	125	W
T_J	Operating Junction Temperature	-55 to +175	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55 to +175	$^\circ\text{C}$
T_L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JC}(\text{IGBT})$	Thermal Resistance, Junction to Case, Max	-	0.6	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max	-	40	$^\circ\text{C/W}$

Notes:

1: Limited by T_{jmax}

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FGA25S125P	FGA25S125P	TO-3PN	-	-	30

Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Off Characteristics						
I _{CES}	Collector Cut-Off Current	V _{CE} = 1250V, V _{GE} = 0V	-	-	1	mA
I _{GES}	G-E Leakage Current	V _{GE} = V _{GES} , V _{CE} = 0V	-	-	±500	nA
On Characteristics						
V _{GE(th)}	G-E Threshold Voltage	I _C = 25mA, V _{CE} = V _{GE}	4.5	6.0	7.5	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 25A, V _{GE} = 15V T _C = 25°C	-	1.8	2.35	V
		I _C = 25A, V _{GE} = 15V T _C = 125°C	-	2.05	-	V
		I _C = 25A, V _{GE} = 15V, T _C = 175°C	-	2.16	-	V
V _{FM}	Diode Forward Voltage	I _F = 25A, T _C = 25°C	-	1.7	2.4	V
		I _F = 25A, T _C = 175°C	-	2.1	-	V
Dynamic Characteristics						
C _{ies}	Input Capacitance	V _{CE} = 30V, V _{GE} = 0V, f = 1MHz	-	2150	-	pF
C _{oes}	Output Capacitance		-	48	-	pF
C _{res}	Reverse Transfer Capacitance		-	36	-	pF
Switching Characteristics						
t _{d(on)}	Turn-On Delay Time	V _{CC} = 600V, I _C = 25A, R _G = 10Ω, V _{GE} = 15V, Resistive Load, T _C = 25°C	-	24	-	ns
t _r	Rise Time		-	250	-	ns
t _{d(off)}	Turn-Off Delay Time		-	502	-	ns
t _f	Fall Time		-	138	-	ns
E _{on}	Turn-On Switching Loss		-	1085	-	μJ
E _{off}	Turn-Off Switching Loss		-	580	-	μJ
E _{ts}	Total Switching Loss		-	1665	-	μJ
t _{d(on)}	Turn-On Delay Time	V _{CC} = 600V, I _C = 25A, R _G = 10Ω, V _{GE} = 15V, Resistive Load, T _C = 175°C	-	21.2	-	ns
t _r	Rise Time		-	304	-	ns
t _{d(off)}	Turn-Off Delay Time		-	490	-	ns
t _f	Fall Time		-	232	-	ns
E _{on}	Turn-On Switching Loss		-	1310	-	μJ
E _{off}	Turn-Off Switching Loss		-	952	-	μJ
E _{ts}	Total Switching Loss		-	2262	-	μJ
Q _g	Total Gate Charge	V _{CE} = 600V, I _C = 25A, V _{GE} = 15V	-	204	-	nC
Q _{ge}	Gate to Emitter Charge		-	15	-	nC
Q _{gc}	Gate to Collector Charge		-	103	-	nC

Typical Performance Characteristics

Figure 1. Typical Output Characteristics

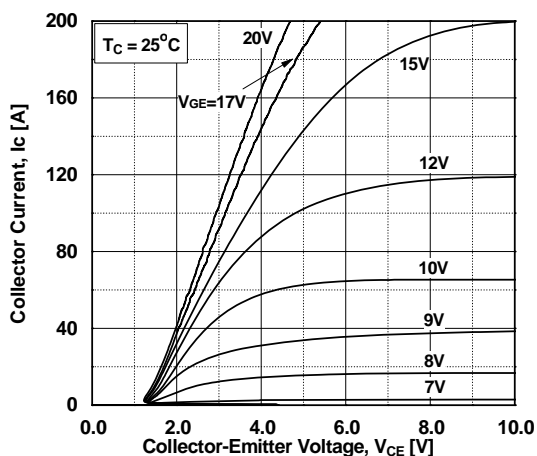


Figure 2. Typical Output Characteristics

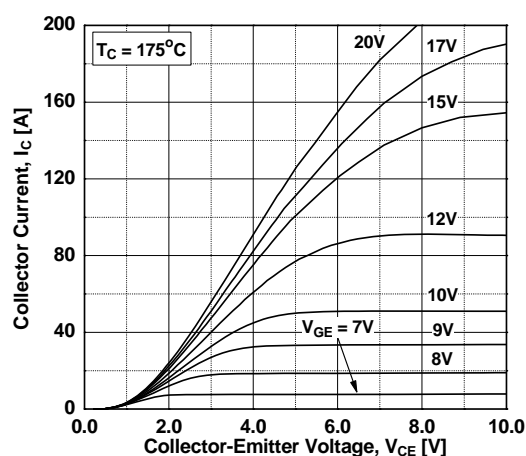


Figure 3. Typical Saturation Voltage Characteristics

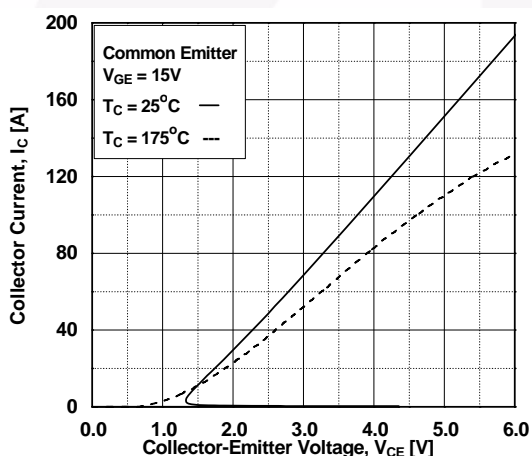


Figure 4. Transfer Characteristics

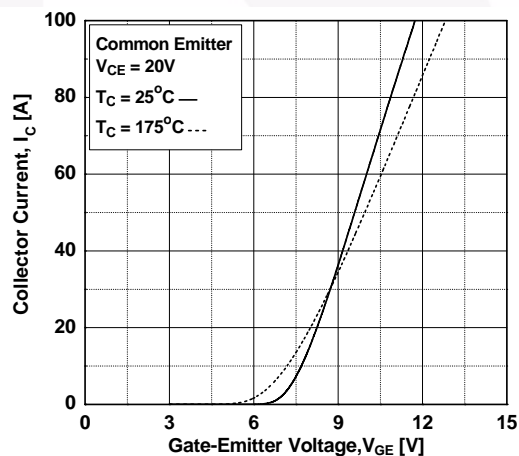


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

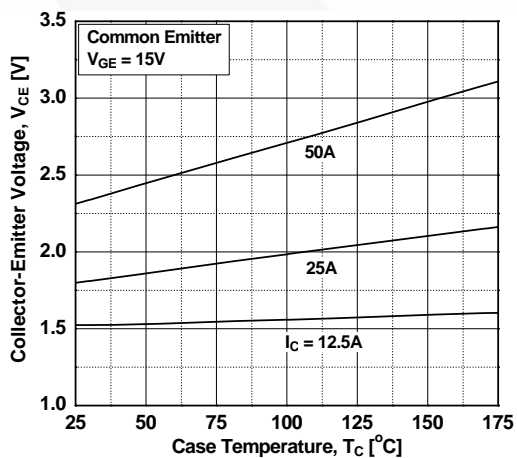
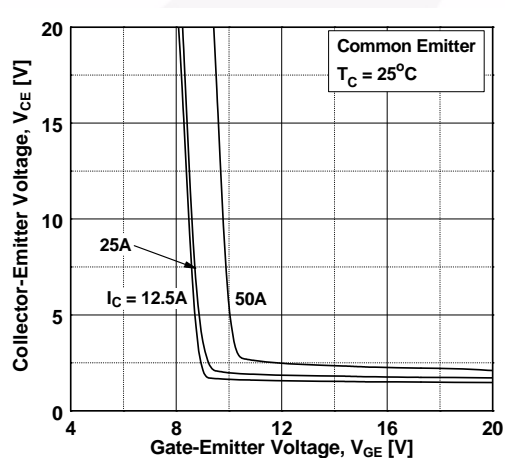


Figure 6. Saturation Voltage vs. Vge



Typical Performance Characteristics

Figure 7. Saturation Voltage vs. V_{GE}

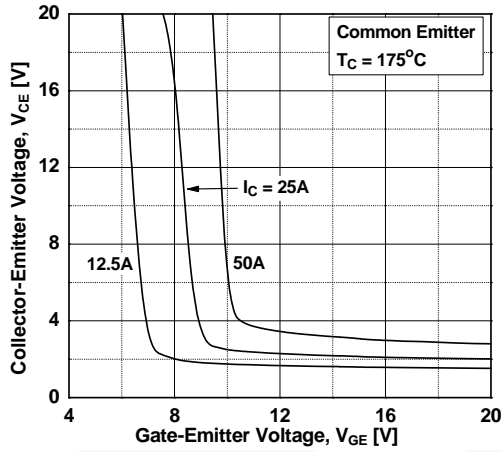


Figure 8. Capacitance Characteristics

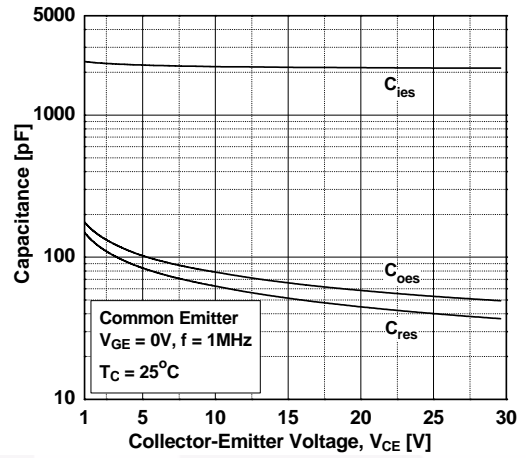


Figure 9. Gate charge Characteristics

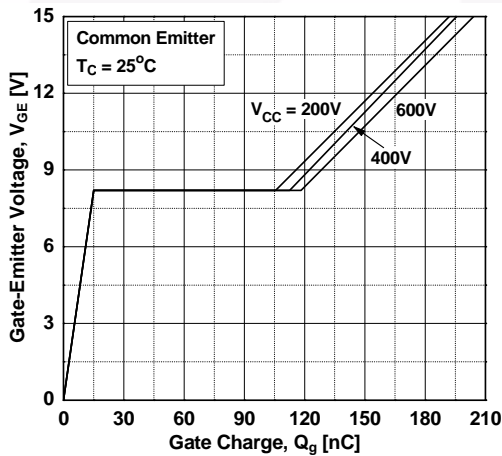


Figure 10. SOA Characteristics

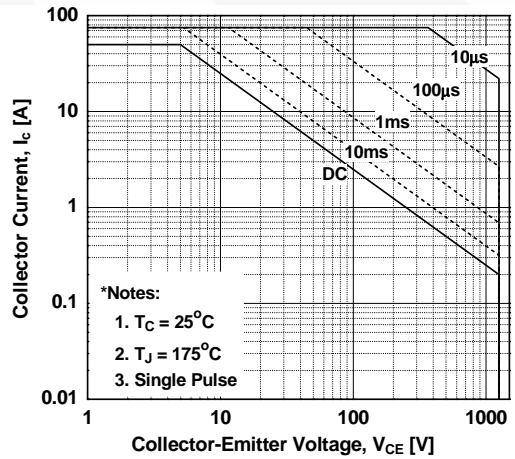


Figure 11. Turn-on Characteristics vs. Gate Resistance

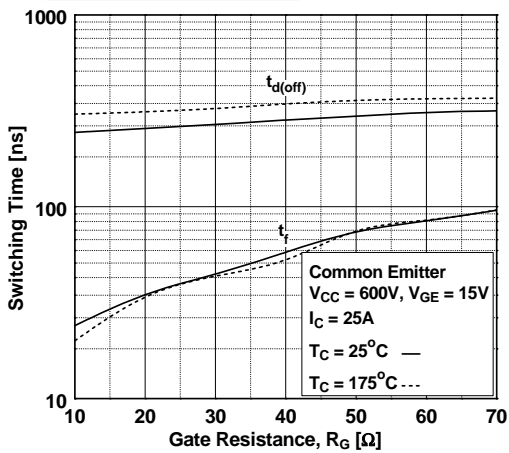
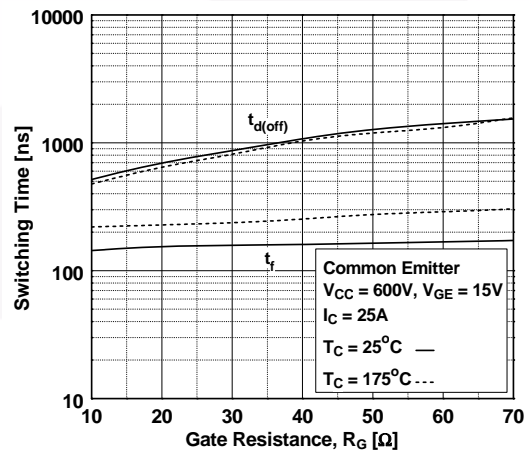


Figure 12. Turn-off Characteristics vs. Gate Resistance



Typical Performance Characteristics

Figure 13. Turn-on Characteristics vs. Collector Current

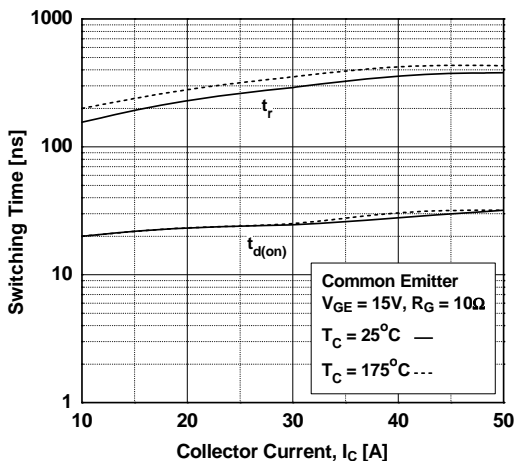


Figure 14. Turn-off Characteristics vs. Collector Current

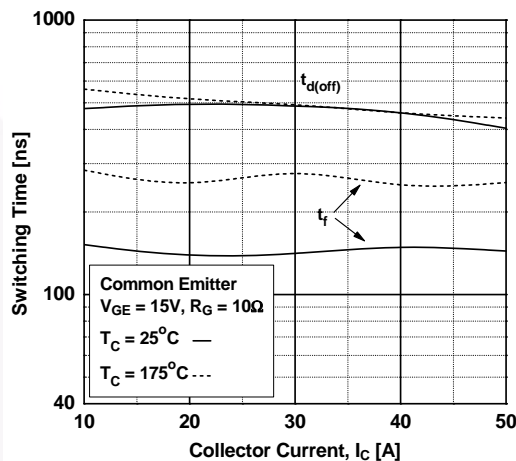


Figure 15. Switching Loss vs. Gate Resistance

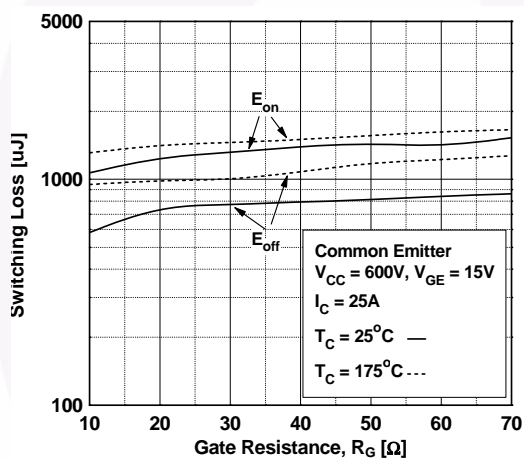


Figure 16. Switching Loss vs. Collector Current

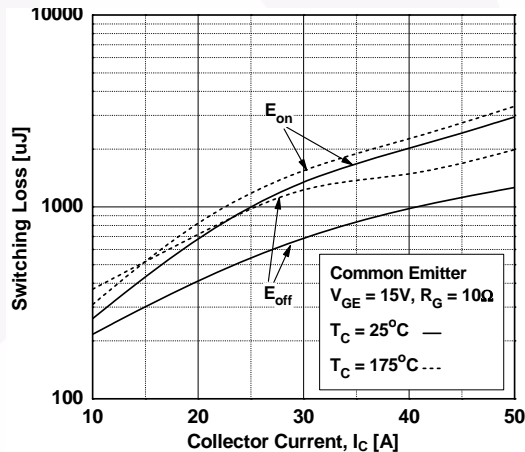


Figure 17. Turn off Switching SOA Characteristics

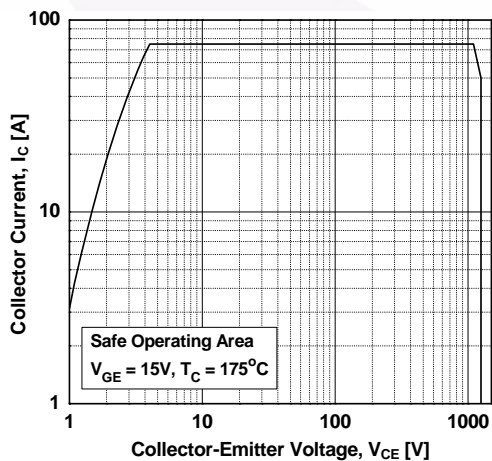
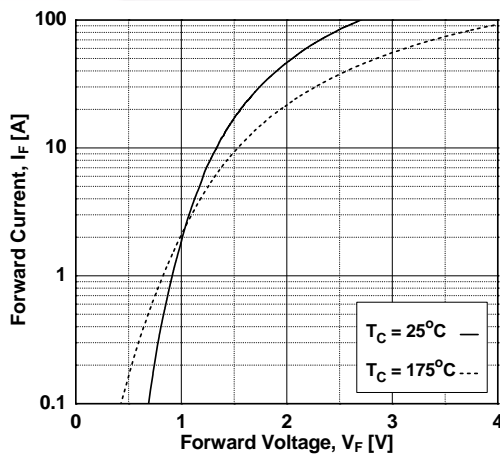
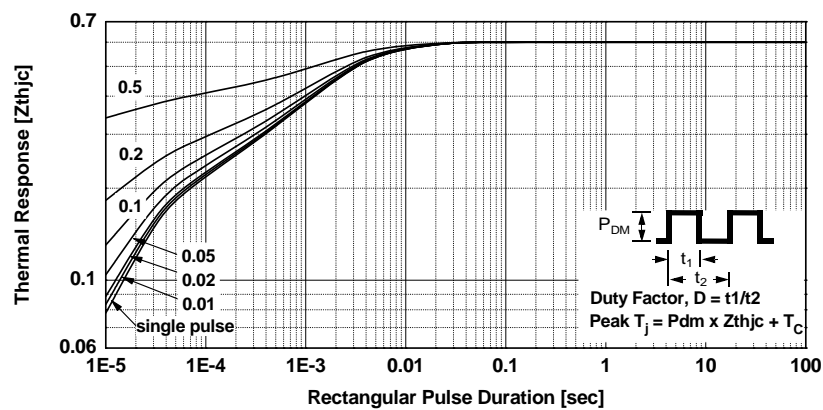


Figure 18. Forward Characteristics

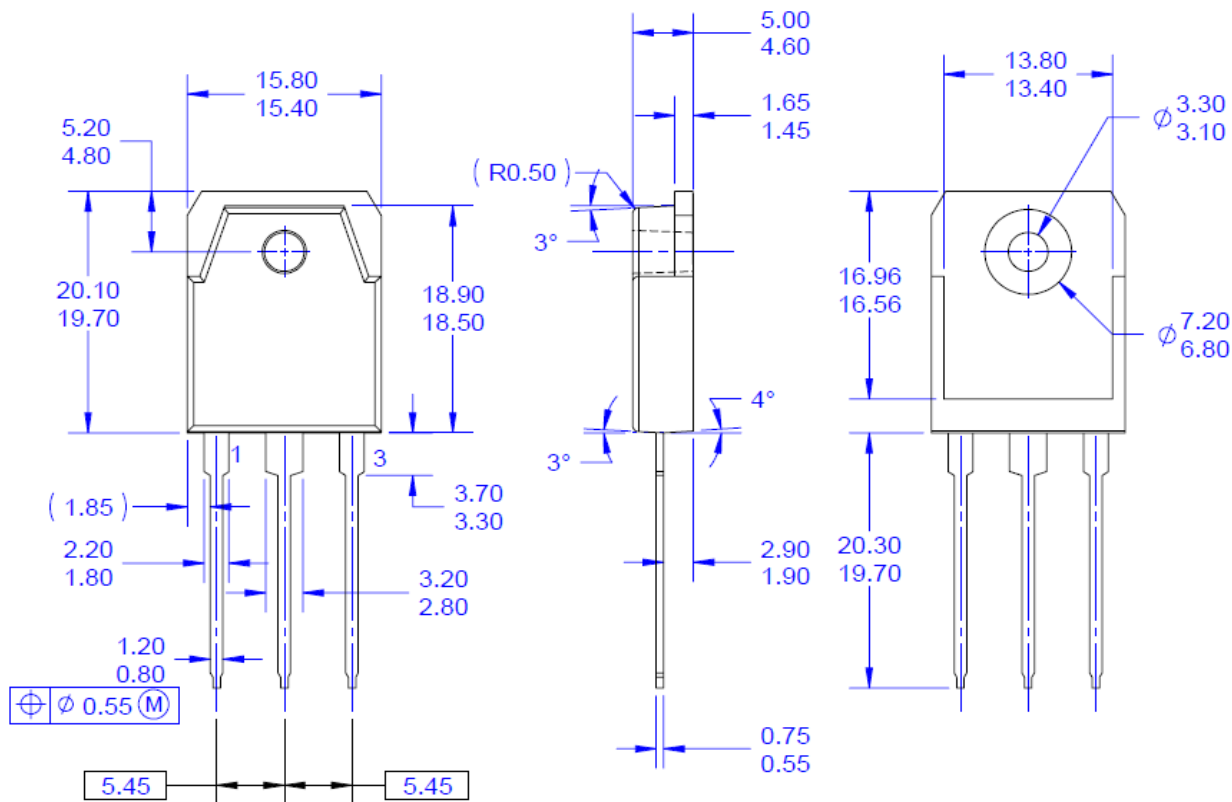


Typical Performance Characteristics

Figure 19. Transient Thermal Impedance of IGBT



Mechanical Dimensions



NOTES: UNLESS OTHERWISE SPECIFIED

- A) THIS PACKAGE CONFORMS TO EIAJ SC-65 PACKAGING STANDARD.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSION AND TOLERANCING PER ASME14.5
- D) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- E) THIS PACKAGE IS INTENDED ONLY FOR T03PN.
- F) DRAWING FILE NAME: T03P03AREV4.

Figure 20. TO-3P 3L - 3LD, T03, PLASTIC, EIAJ SC-65

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Dimensions in Millimeters



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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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